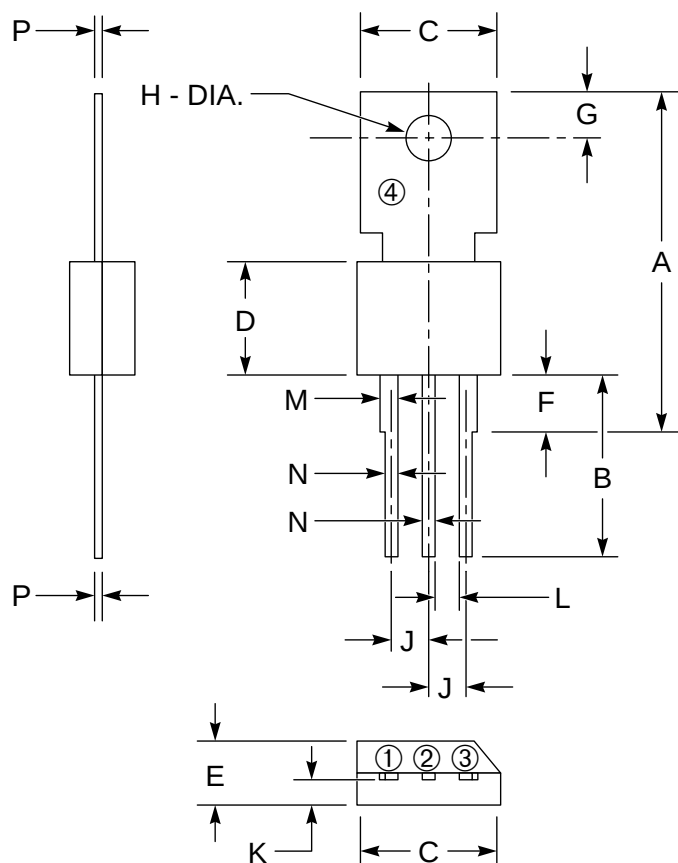


Triac

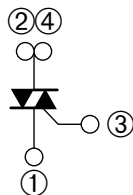
3 Amperes/400-600 Volts

OUTLINE DRAWING



CONNECTION DIAGRAM

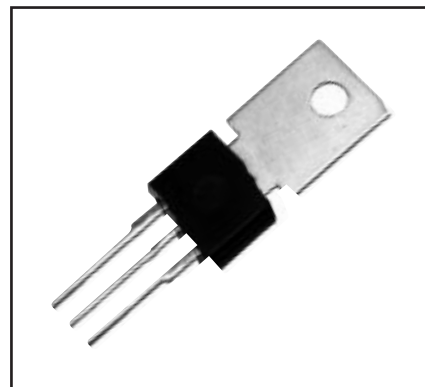
- ① T1 TERMINAL
- ② T2 TERMINAL
- ③ GATE TERMINAL
- ④ T2 TERMINAL



Outline Drawing (Conforms to TO-202)

Dimensions	Inches	Millimeters
A	0.93 ± 0.02	23.7 ± 0.5
B	0.47 Min.	12.0 Min.
C	0.39 Max.	10.0 Max.
D	0.31 Max.	8.0 Max.
E	0.18	4.5
F	0.16 Max.	4.0 Max.
G	0.126 ± 0.008	3.2 ± 0.2

Dimensions	Inches	Millimeters
H	0.126 ± 0.004 Dia.	3.2 ± 0.1 Dia.
J	0.10	2.5
K	0.061	1.55
L	0.059 Max.	1.5 Max.
M	0.047	1.2
N	0.035	0.8
P	0.02	0.5



Description:

A triac is a solid state silicon AC switch which may be gate triggered from an off-state to an on-state for either polarity of applied voltage.

Features:

- ☐ Glass Passivation

Applications:

- ☐ AC Switch
- ☐ Motor Controls
- ☐ Lighting
- ☐ Solid State Relay

Ordering Information:

Example: Select the complete seven or eight digit part number you desire from the table - i.e. BCR3AM-8 is a 400 Volt, 3 Ampere Triac.

Type	V _{DRM} Volts	Code
BCR3AM	400	-8
	600	-12

BCR3AM

Triac

3 Amperes/400-600 Volts

Absolute Maximum Ratings, $T_a = 25^\circ\text{C}$ unless otherwise specified

Ratings	Symbol	BCR3AM-8	BCR3AM-12	Units
Repetitive Peak Off-state Voltage	VDRM	400	600	Volts
Non-repetitive Peak Off-state Voltage	VDSM	500	720	Volts
On-state Current, $T_c = 86^\circ\text{C}$	IT(RMS)	3	3	Amperes
Non-repetitive Peak Surge, One Cycle (60 Hz)	ITSM	30	30	Amperes
I^2t for Fusing, $t = 8.3$ msec	I^2t	3.7	3.7	A2sec
Peak Gate Power Dissipation, 20 msec	PGM	3	3	Watts
Average Gate Power Dissipation	PG(avg)	0.3	0.3	Watts
Peak Gate Current	IGM	0.5	0.5	Amperes
Peak Gate Voltage	VGM	6	6	Volts
Storage Temperature	T_{stg}	-40 to 125	-40 to 125	$^\circ\text{C}$
Operating Temperature	T_j	-40 to 125	-40 to 125	$^\circ\text{C}$
Weight	—	1.6	1.6	Grams

Electrical and Thermal Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics*	Symbol	Test Conditions (Trigger Mode)				BCR3AM			
		V _D	R _L	R _G	T _j	Min.	Typ.	Max.	Units
Gate Parameters									
DC Gate Trigger Current									
MT2+ Gate+	I _{GT}	6V	6Ω	330Ω	25°C	—	—	30	mA
MT2+ Gate–		6V	6Ω	330Ω	25°C	—	—	30	mA
MT2– Gate–		6V	6Ω	330Ω	25°C	—	—	30	mA
DC Gate Trigger Voltage									
MT2+ Gate+	V _{GT}	6V	6Ω	330Ω	25°C	—	—	1.5	Volts
MT2+ Gate–		6V	6Ω	330Ω	25°C	—	—	1.5	Volts
MT2– Gate–		6V	6Ω	330Ω	25°C	—	—	1.5	Volts
DC Gate Non-trigger Voltage									
All	V _{GD}	1/2 V _{DRM}	—	—	125°C	0.2	—	—	Volts

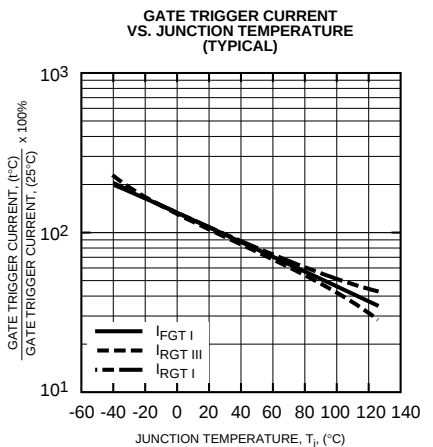
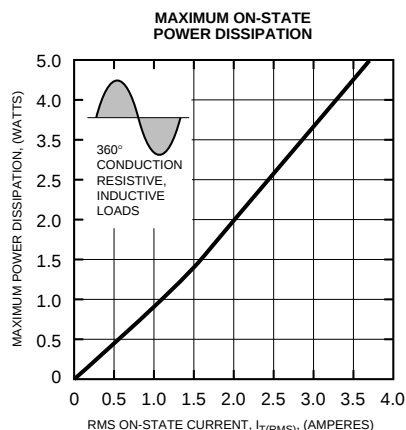
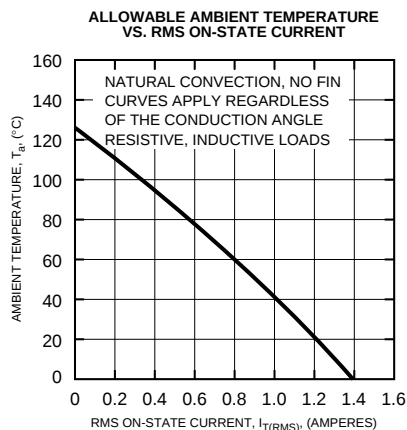
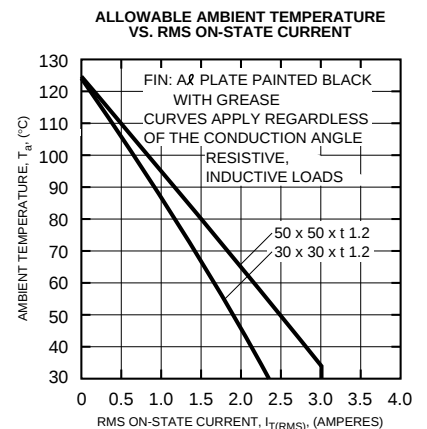
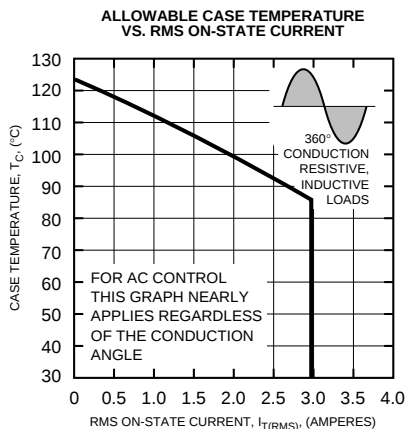
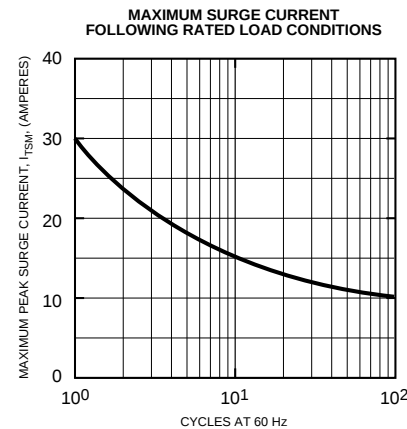
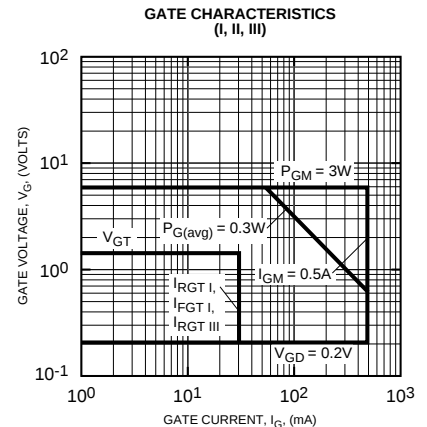
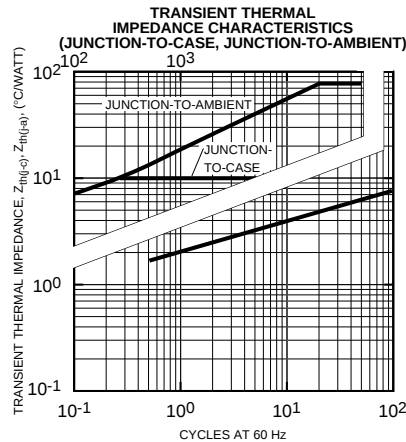
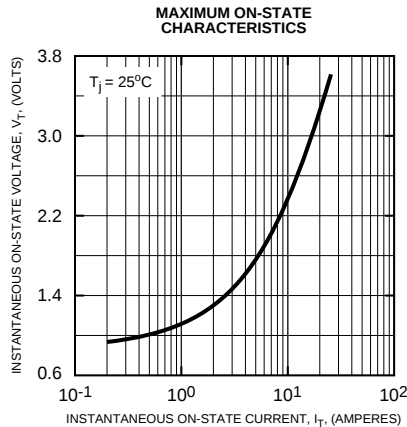
*Characteristic values apply for either polarity of Main Terminal 2 referenced to Main Terminal 1.

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance, Junction-to-case	$R_{th(j-c)}$	—	—	—	10	$^\circ\text{C/W}$
Steady State Thermal Resistance, Junction-to-ambient	$R_{th(j-a)}$	—	—	—	80	$^\circ\text{C/W}$
Voltage – Blocking State Repetitive Off-state Current	I_{DRM}	Gate Open Circuited, $V_D = V_{DRM}$, $T_j = 125^\circ\text{C}$	—	—	2	mA
Current – Conducting State Peak On-state Voltage	V_{TM}	$T_c = 25^\circ\text{C}$, $I_{TM} = 4.5\text{A}$	—	—	1.5	Volts
Critical Rate-of-rise of Commutating Off-state Voltage (Commutating dv/dt) (Switching)	$(dv/dt)_c$	$T_j = 125^\circ\text{C}$, $V_D = 400\text{V}$, Gate Open Circuited, Commutating $(di/dt) = -2\text{A/ms}$	5	—	—	$\text{V}/\mu\text{s}$

BCR3AM

Triac

3 Amperes/400-600 Volts



BCR3AM

Triac

3 Amperes/400-600 Volts

